

5-30GHz ATTENUATOR

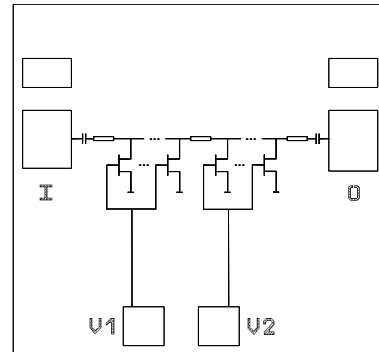
GaAs Monolithic Microwave IC

Description

The CHT4690-99F is a variable 5-30GHz attenuator designed for a wide range of applications, from military to commercial communication systems. The backside of the chip is both RF and DC grounds. This helps simplify the assembly process.

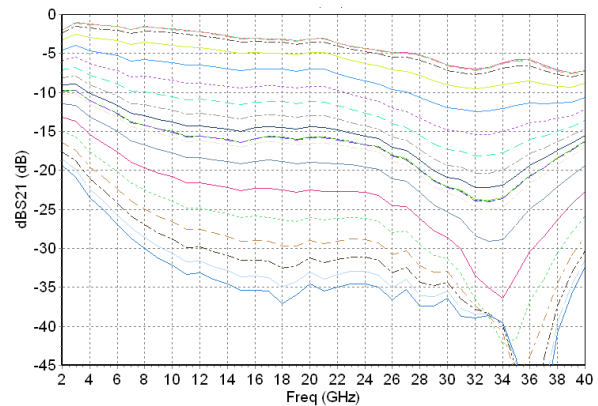
The circuit is manufactured with a MESFET process, 0.7µm gate length, via holes through the substrate and air bridges.

It is supplied in chip form.



Main Features

- Broadband performance: 5-30GHz
- 25dBm typical input 1dB compression point (any attenuation)
- 30dB dynamic range
- DC bias : $-5V < V1 < 0V$; $-5V < V2 < 0V$
- Chip size: 1.5x1.5x0.1mm



Main Characteristics

Tamb. = 25°C

Symbol	Parameter	Min	Typ	Max	Unit
Fin	Input frequency range	5		30	GHz
Min Att.	S21 (V1=-5V;V2=-5V) (5 to 12GHz)		2.5	3	dB
	S21 (V1=-5V;V2=-5V) (12 to 30GHz)		6.5	7.5	dB
Max Att.	S21 (V1=0V;V2=0V) (5 to 12GHz)	22	25		dB
	S21 (V1=0V;V2=0V) (12 to 30GHz)	27	34		dB
Pin1dB	Input 1dB compression point (any attenuation)	24	25		dBm

ESD Protection: Electrostatic discharge sensitive device. Observe handling precautions!

Electrical Characteristics

Tamb. = 25°C

Symbol	Parameter	Min	Typ	Max	Unit
Fin	Input frequency range	5		30	GHz
Min Att.	S21 (V1=-5V;V2=-5V) (5 to 12GHz)		2.5	3	dB
	S21 (V1=-5V;V2=-5V) (12 to 30GHz)		6.5	7.5	dB
Max Att.	S21 (V1=0V;V2=0V) (5 to 12GHz)	22	25		dB
	S21 (V1=0V;V2=0V) (12 to 30GHz)	27	34		dB
RLin	Input Return loss (any Att) (5 to 30GHz)			-8	dB
RLout	Ouput Return loss (any Att) (5 to 8GHz)			-4	dB
	Ouput Return loss (any Att) (8 to 30GHz)			-7	dB
Pin1dB	Input 1dB compression point (any Att) (5 to 25GHz)	24	25		dBm
C/I3	C/I3 @ Pin/tone=12dBm (any Att) (up to 26GHz)	36	40		dB

Absolute Maximum Ratings ⁽¹⁾

Tamb. = +25°C

Symbol	Parameter	Values	Unit
V1	V1 control voltage	-6V to +0.6V	V
V2	V2 control voltage	-6V to +0.6V	V
Pin	RF input power	30	dBm
Ta	Operating temperature range	-40 to +95	°C
Tstg	Storage temperature range	-55 to +155	°C

(1) Operation of this device above anyone of these parameters may cause permanent damage.

Typical Bias Conditions

Temperature = +25°C

Symbol	Parameter	Values	Unit
V1	V1 control voltage	-5 to 0	V
V2	V2 control voltage	-5 to 0	V

Typical results

Chip Typical Response (On wafer Sij)

Tamb = +25°C, V1 = -5V & V2= -5V

Freq (GHz)	dBS11 (dB)	PhS11 (°)	dBS12 (dB)	PhS12 (°)	dBS21 (dB)	PhS21 (°)	dBS22 (dB)	PhS22 (°)
2	-6.29	-104.78	-2.01	-9.01	-1.98	-9.34	-6.22	-97.53
3	-13.90	-142.32	-1.08	-46.74	-1.04	-47.05	-13.82	-126.13
4	-33.49	103.94	-1.27	-78.74	-1.25	-79.12	-27.95	-69.61
5	-18.92	-5.76	-1.42	-104.45	-1.38	-104.65	-19.19	-18.49
6	-15.43	-27.95	-1.52	-131.80	-1.49	-131.98	-14.88	-52.69
7	-13.73	-53.65	-1.94	-155.91	-1.89	-156.07	-14.92	-74.29
8	-15.09	-68.43	-1.58	179.46	-1.55	179.18	-15.12	-102.17
9	-16.08	-74.62	-1.72	153.40	-1.68	153.18	-19.19	-140.64
10	-16.59	-73.62	-1.86	127.70	-1.80	127.51	-26.46	148.17
11	-16.95	-64.41	-2.11	103.34	-2.04	103.15	-19.90	42.75
12	-14.53	-70.07	-2.26	78.02	-2.20	77.64	-15.17	4.12
13	-13.73	-75.66	-2.50	53.37	-2.44	53.10	-12.54	-20.65
14	-12.55	-82.11	-2.82	29.21	-2.76	28.89	-10.75	-41.79
15	-11.30	-89.63	-3.08	7.21	-3.02	6.92	-9.48	-62.60
16	-11.29	-108.06	-3.06	-16.89	-3.00	-17.20	-9.80	-84.27
17	-11.56	-127.91	-3.17	-38.98	-3.12	-39.35	-10.69	-104.87
18	-14.44	-138.27	-3.19	-63.43	-3.14	-63.66	-12.57	-123.19
19	-18.03	-154.90	-3.42	-85.65	-3.37	-85.77	-17.85	-136.13
20	-31.46	-65.09	-3.15	-107.92	-3.09	-108.07	-24.60	-74.92
21	-15.91	-56.73	-3.11	-135.35	-3.06	-135.53	-15.74	-46.79
22	-11.85	-81.87	-3.65	-160.66	-3.62	-160.76	-11.06	-67.33
23	-11.09	-104.33	-4.13	176.26	-4.05	176.14	-9.92	-88.92
24	-12.09	-121.81	-4.38	153.99	-4.32	153.77	-9.57	-105.06
25	-13.45	-129.91	-4.60	130.21	-4.54	129.98	-10.03	-120.22
26	-15.14	-142.57	-4.93	105.98	-4.87	105.80	-11.49	-132.20
27	-20.61	-151.15	-4.98	81.66	-4.90	81.38	-13.59	-133.90
28	-22.21	-48.69	-5.19	53.71	-5.14	53.38	-14.94	-123.67
29	-13.40	-56.86	-5.84	26.74	-5.76	26.39	-13.19	-115.78
30	-9.33	-83.86	-6.53	1.04	-6.47	0.67	-11.12	-124.99
31	-9.26	-107.23	-6.86	-23.20	-6.81	-23.52	-10.14	-136.08
32	-9.16	-124.74	-7.10	-48.20	-7.04	-48.73	-9.70	-155.88
33	-10.96	-143.12	-6.87	-72.14	-6.79	-72.51	-11.28	-173.54
34	-15.41	-159.05	-6.31	-99.51	-6.23	-99.96	-13.59	160.74
35	-24.19	-104.04	-5.88	-128.72	-5.81	-129.15	-23.56	143.93
36	-14.66	-71.35	-5.85	-159.29	-5.77	-159.70	-22.62	-104.16
37	-10.13	-86.82	-6.58	173.48	-6.50	173.15	-13.93	-110.93
38	-8.18	-105.93	-7.22	150.56	-7.12	150.10	-11.22	-138.54
39	-7.36	-123.76	-7.60	131.28	-7.49	131.09	-10.42	-158.76
40	-7.57	-143.67	-7.27	115.53	-7.17	115.09	-9.23	176.23

Typical results

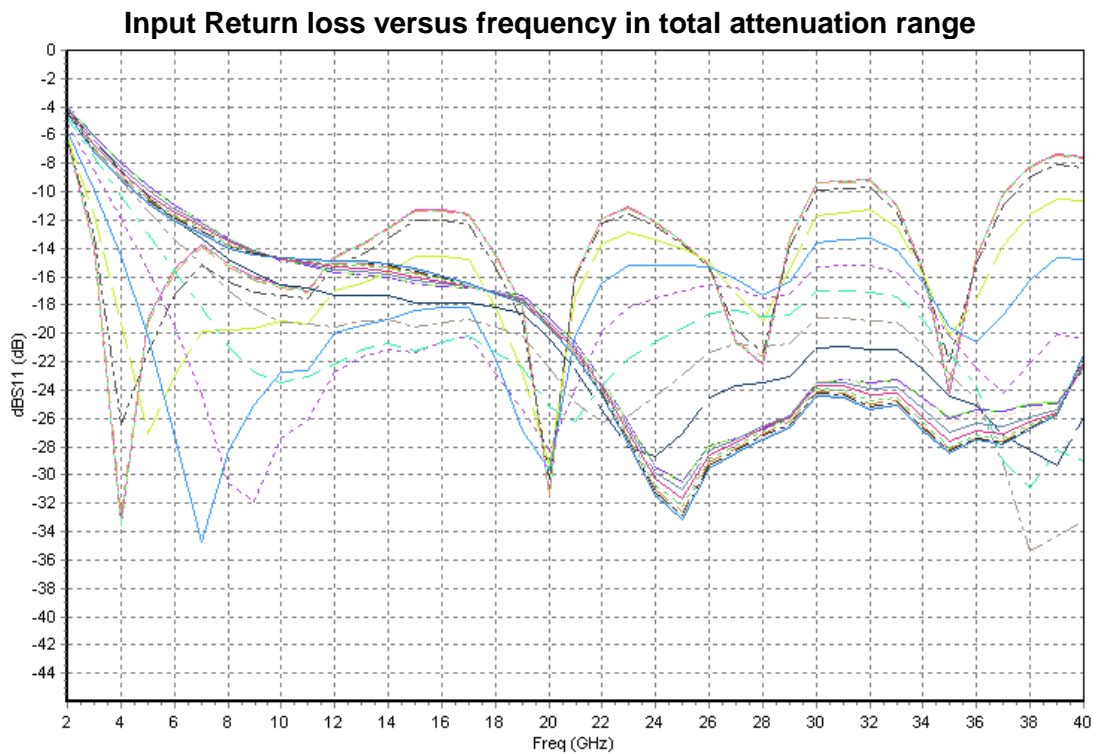
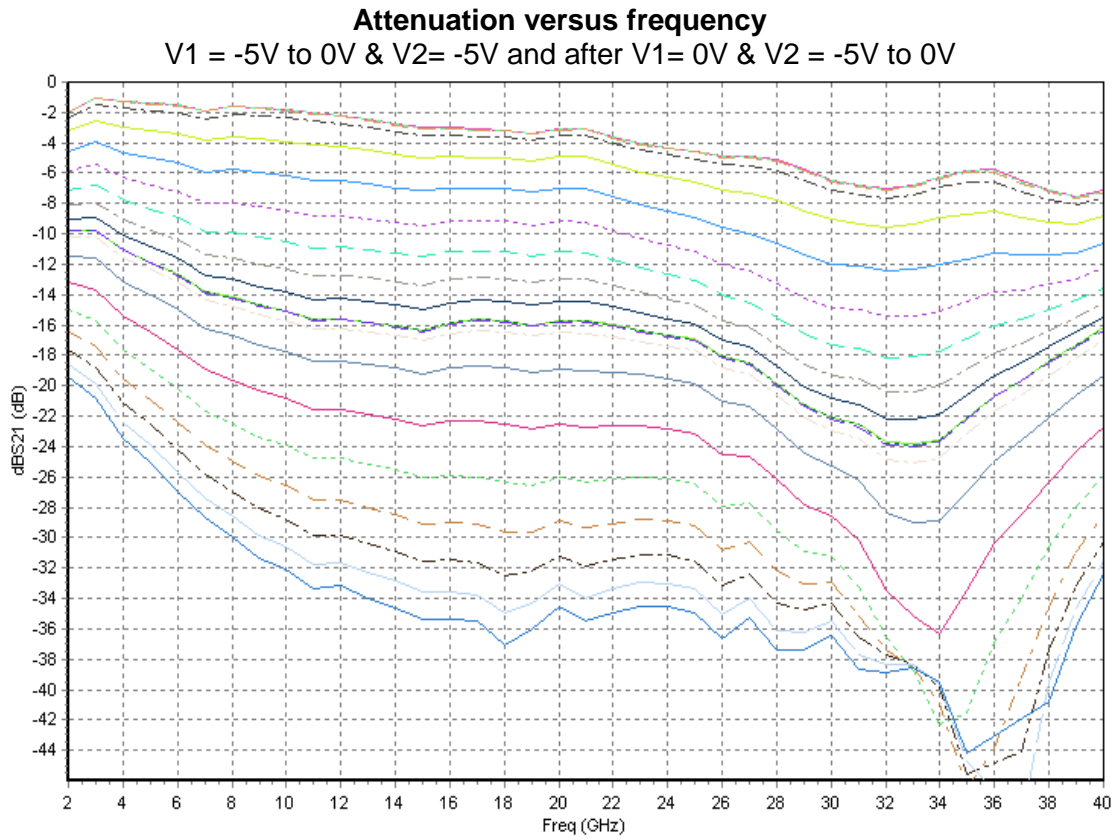
Chip Typical Response (On wafer Sij)

Tamb = +25°C, V1 = 0V & V2= 0V

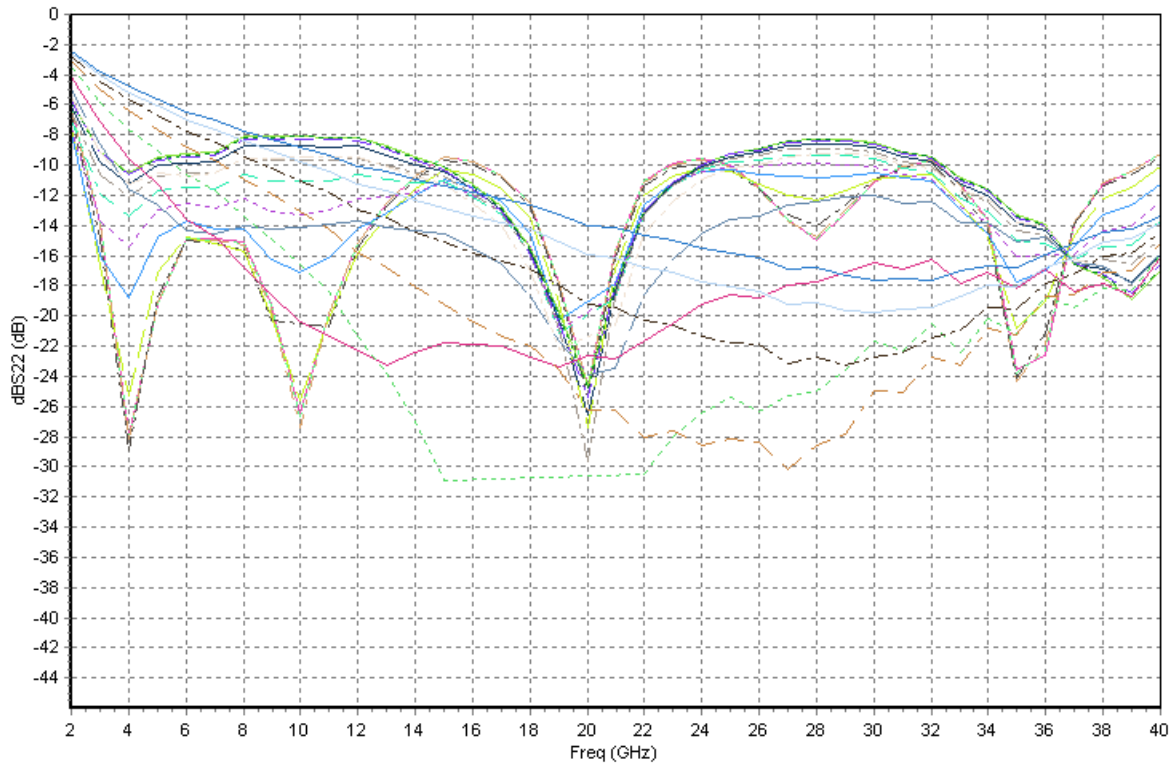
Freq (GHz)	dBS11 (dB)	PhS11 (°)	dBS12 (dB)	PhS12 (°)	dBS21 (dB)	PhS21 (°)	dBS22 (dB)	PhS22 (°)
2	-4.44	-143.24	-19.44	-26.13	-19.40	-26.38	-2.40	-126.78
3	-7.20	-171.22	-20.89	-76.86	-20.86	-77.07	-3.79	-155.50
4	-9.10	174.49	-23.49	-113.84	-23.47	-114.12	-4.82	-173.85
5	-10.80	164.52	-25.09	-145.87	-25.05	-146.02	-5.67	172.68
6	-12.09	159.75	-26.99	-173.25	-26.95	-173.28	-6.45	162.93
7	-12.93	156.90	-28.74	160.34	-28.69	160.31	-7.04	154.27
8	-13.99	154.84	-30.05	136.61	-30.01	136.37	-7.72	147.14
9	-14.44	154.65	-31.34	112.68	-31.30	112.60	-8.25	140.61
10	-14.69	154.72	-32.15	90.56	-32.10	90.54	-8.84	134.77
11	-14.72	151.66	-33.42	71.27	-33.35	71.25	-9.35	129.86
12	-14.91	150.39	-33.25	49.61	-33.19	49.38	-10.10	125.48
13	-14.90	146.38	-34.01	29.42	-33.95	29.35	-10.42	122.02
14	-15.05	141.41	-34.69	10.49	-34.61	10.53	-10.97	117.52
15	-15.44	134.90	-35.49	-9.63	-35.42	-9.82	-11.41	113.26
16	-15.91	127.63	-35.48	-22.24	-35.33	-22.55	-11.81	108.79
17	-16.49	121.21	-35.64	-38.98	-35.50	-39.00	-12.21	104.88
18	-17.20	112.41	-37.09	-55.23	-37.06	-55.58	-12.61	98.91
19	-17.85	101.71	-35.96	-62.20	-35.97	-62.19	-13.29	95.15
20	-19.65	85.00	-34.60	-84.28	-34.55	-84.31	-14.01	90.96
21	-21.55	71.59	-35.62	-104.90	-35.48	-104.90	-14.15	88.83
22	-24.36	50.12	-35.06	-121.53	-34.97	-121.54	-14.66	83.28
23	-27.84	26.69	-34.63	-142.27	-34.55	-142.68	-14.93	81.81
24	-31.47	-8.22	-34.59	-161.79	-34.52	-162.19	-15.47	77.97
25	-33.10	-47.36	-34.97	176.00	-34.95	176.30	-15.86	74.21
26	-29.54	-67.08	-36.67	170.42	-36.60	170.40	-16.13	68.56
27	-28.46	-98.46	-35.44	152.57	-35.32	152.17	-16.87	64.47
28	-27.50	-97.94	-37.59	134.66	-37.42	134.22	-16.78	62.16
29	-26.66	-105.16	-37.41	137.29	-37.37	136.97	-17.33	59.71
30	-24.45	-120.07	-36.45	118.83	-36.43	118.60	-17.65	62.80
31	-24.56	-139.96	-38.67	102.14	-38.69	101.74	-17.51	57.70
32	-25.41	-148.35	-38.96	107.86	-38.89	107.48	-17.68	60.32
33	-25.09	-152.31	-38.69	93.25	-38.58	93.33	-17.01	50.49
34	-26.83	-175.25	-39.68	75.15	-39.48	75.61	-16.68	54.96
35	-28.46	168.50	-44.22	42.32	-44.23	40.54	-16.74	48.74
36	-27.53	140.64	-57.99	14.39	-57.42	15.21	-15.91	53.83
37	-27.82	106.98	-51.31	-100.68	-51.46	-100.36	-15.24	45.02
38	-26.79	80.89	-40.98	-130.65	-40.84	-130.90	-14.40	42.19
39	-25.83	57.55	-35.91	-158.28	-35.85	-158.46	-14.25	35.29
40	-21.50	51.16	-32.54	-174.93	-32.44	-174.88	-13.39	44.33

Typical Results on wafer

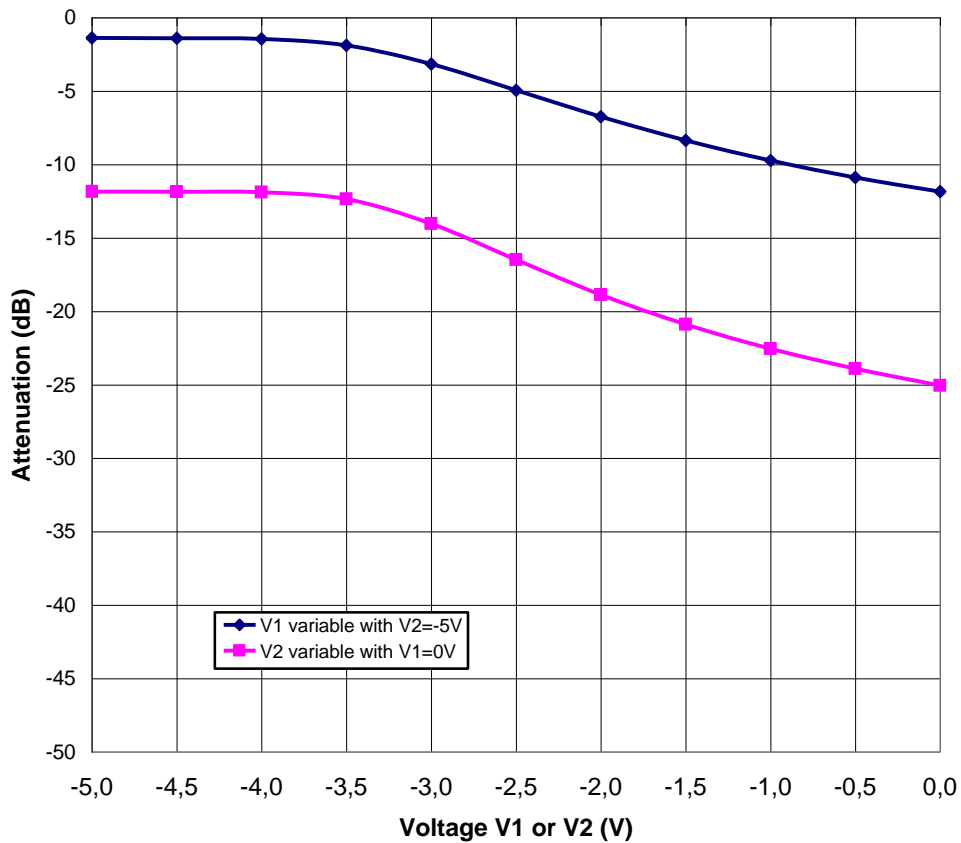
Tamb = +25°C



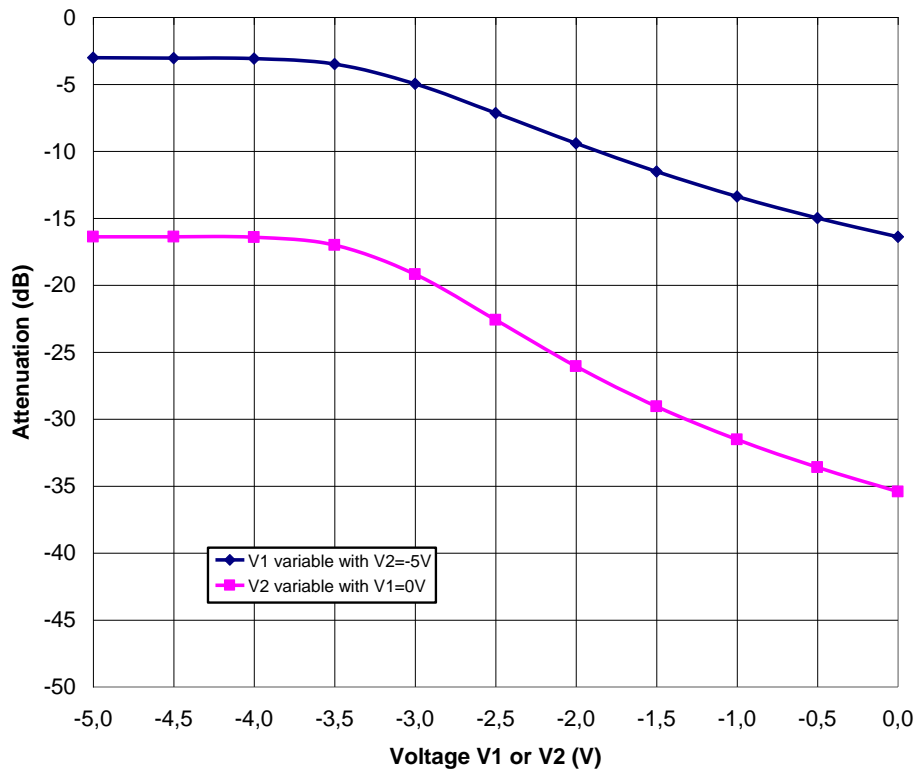
Output Return loss versus frequency in total attenuation range



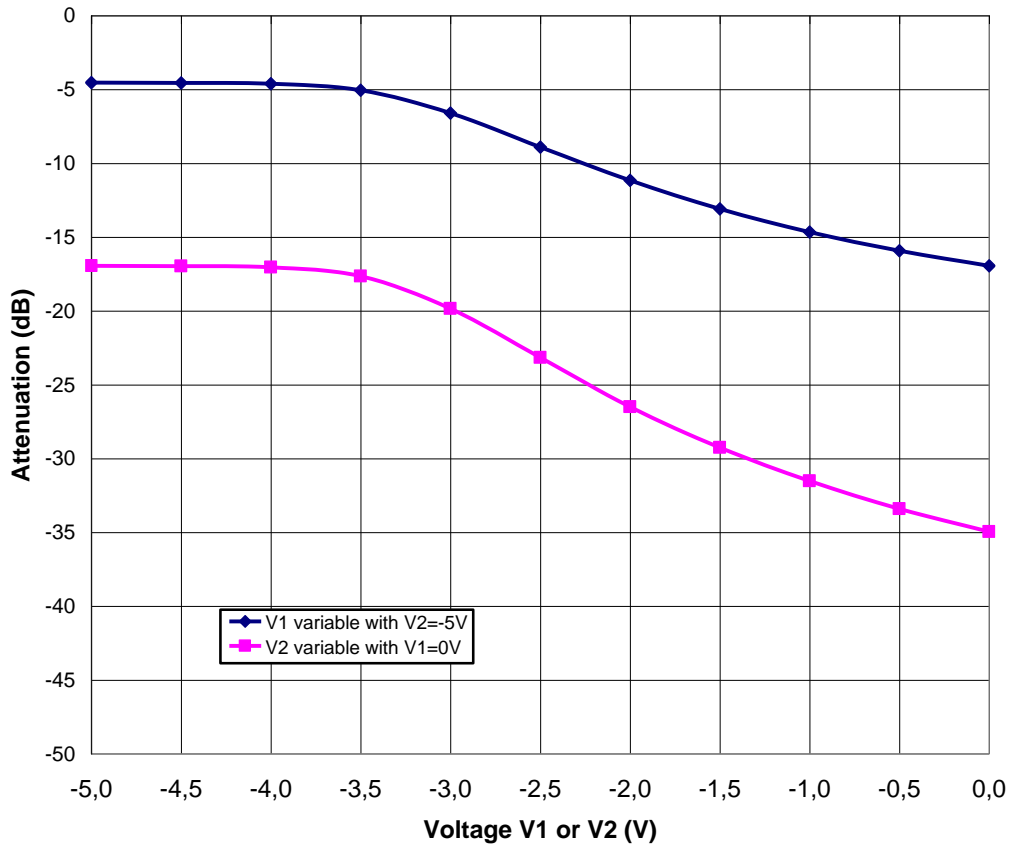
Attenuation control at 5GHz



Attenuation control at 15GHz

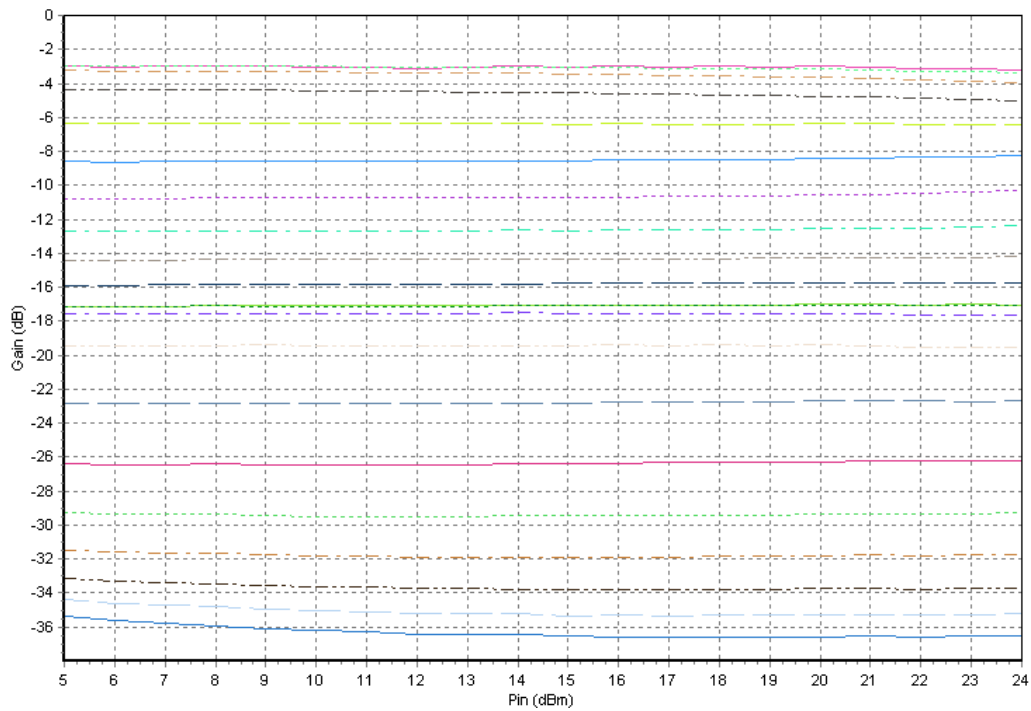


Attenuation control at 25GHz

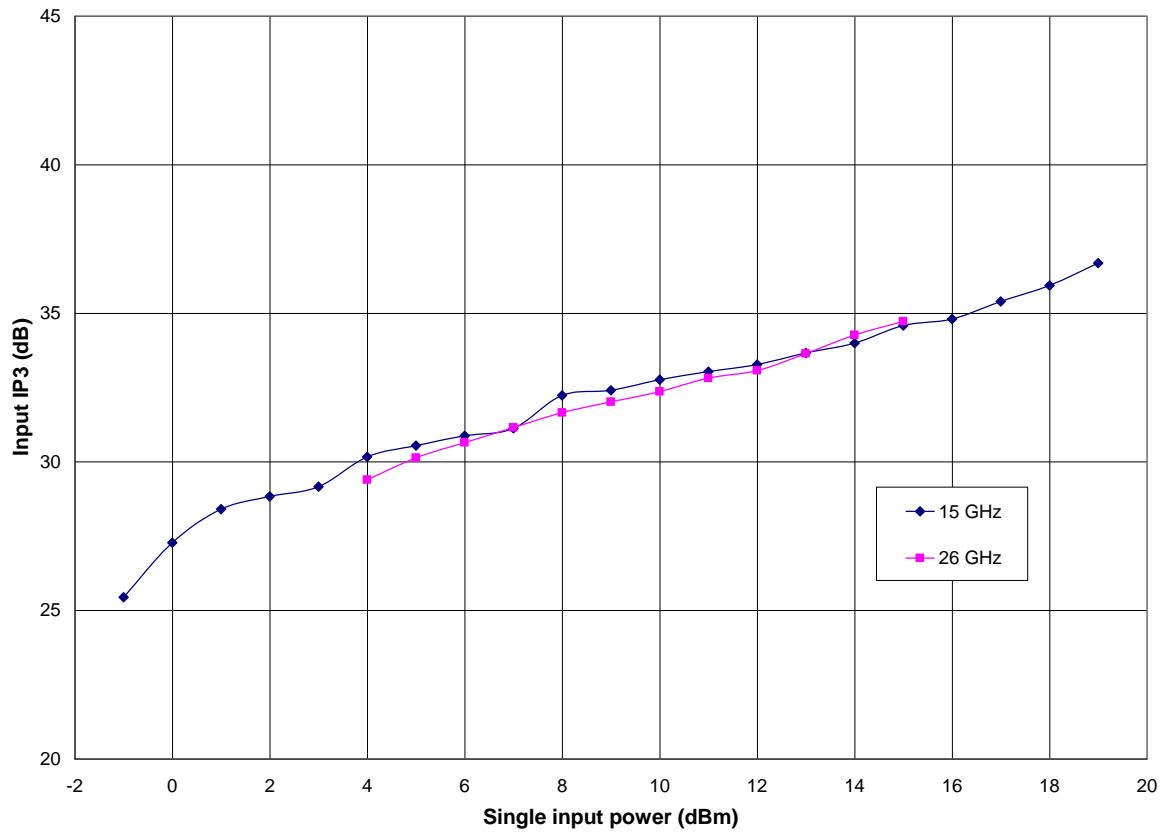


Attenuation versus input power @ 20GHz

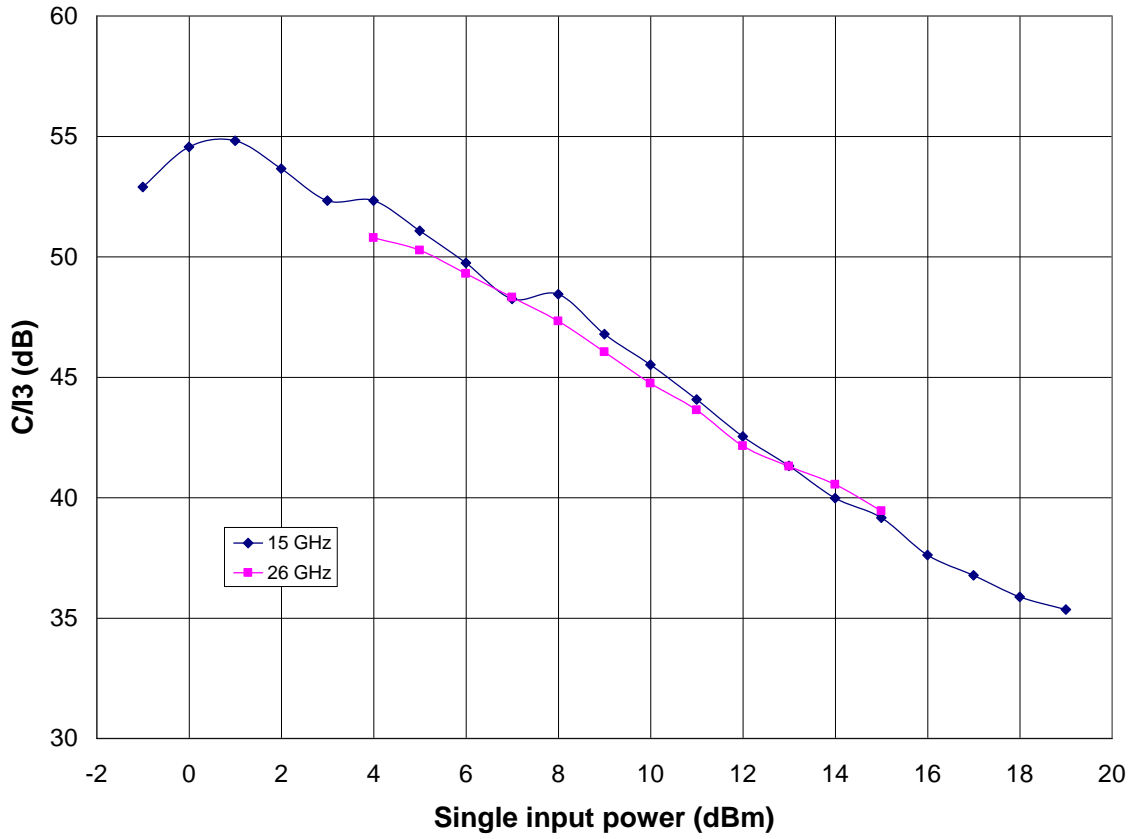
V1 = -5V to 0V & V2= -5V and after V1= 0V & V2 = -5V to 0V



Input IP3 versus input power
V1 = -3.5V & V2= -5V (worst case area for the linearity)



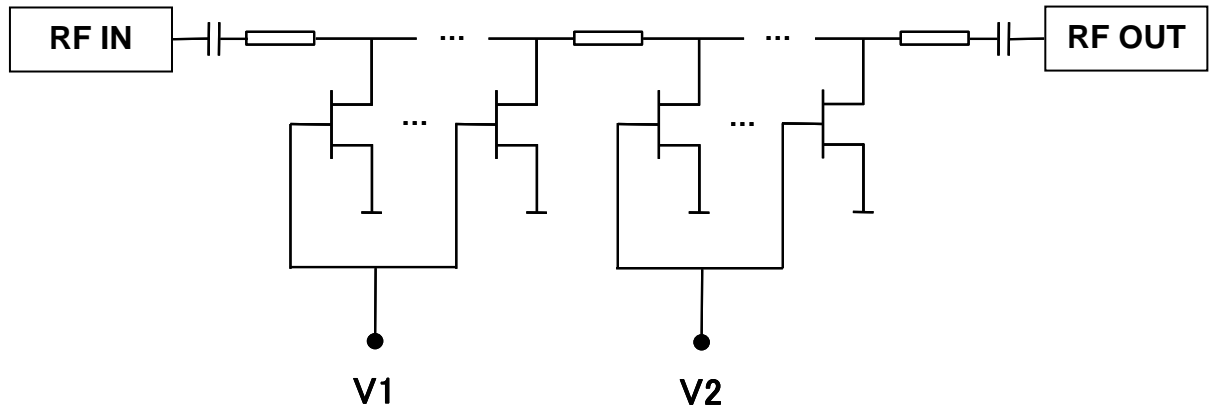
C/I3 versus input power
V1 = -3.5V & V2 = -5V (worst case area for the linearity)



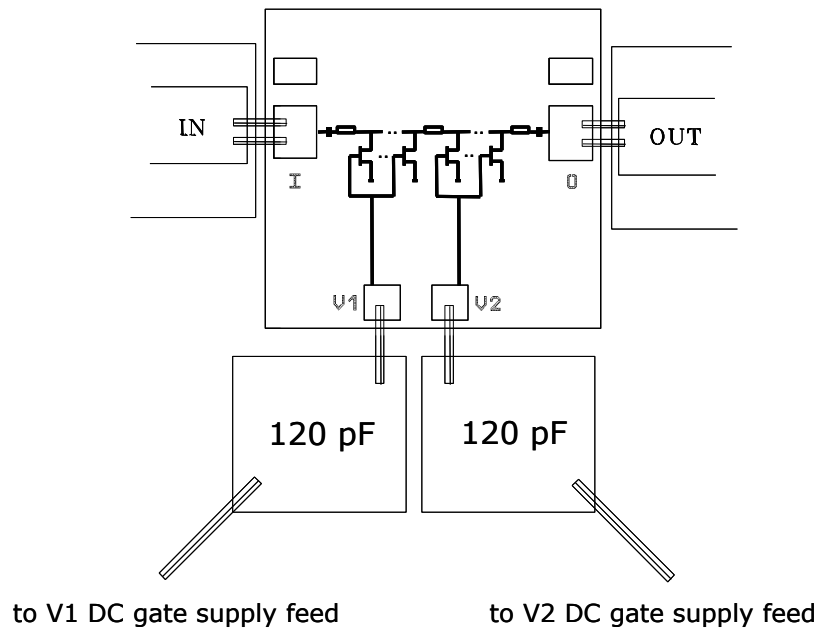
Biasing sequence

To obtain good performances in linearity, biasing voltage should be applied as following:

- Control of 1st stage attenuation with V1 from -5V to 0V, with V2 fixed at -5V
- Control of 2nd stage with V2 from -5V to 0V, with V1 fixed at 0V

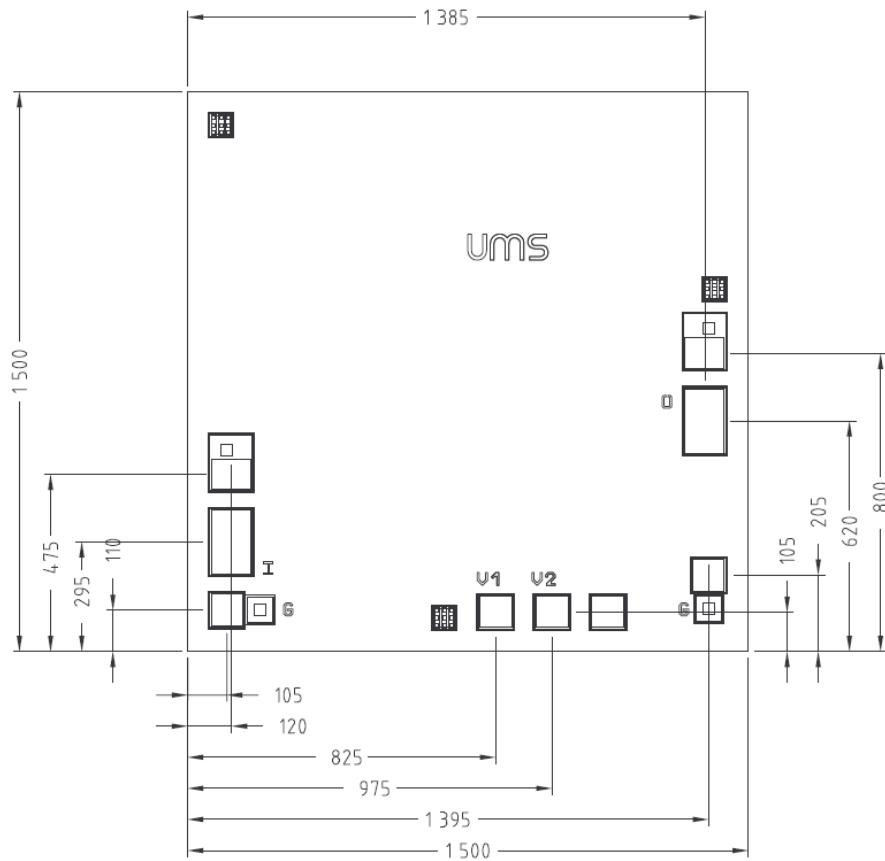


Chip Assembly and Mechanical Data



Note: Supply feed might be capacitively bypassed. 25µm diameter gold wire is to be preferred.

Bonding pad positions



UNITS : μm
Tol : $\pm 35\mu\text{m}$

(Chip thickness: 100 μm . All dimensions are in micrometers)

Ordering Information

Chip form:

CHT4690-99F/00

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